

## TrenchT2™ **Power MOSFET**

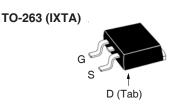
## IXTA300N04T2 IXTP300N04T2

N-Channel Enhancement Mode Avalanche Rated



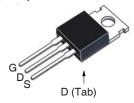
$V_{\rm DSS}$	=	40V
I <sub>D25</sub>	=	300A
R <sub>DS(on)</sub>	≤	$2.5$ m $\Omega$





Symbol	Test Conditions	Maximum R	atings
V <sub>DSS</sub>	T <sub>J</sub> = 25°C to 175°C	40	V
V <sub>DGR</sub>	$T_J = 25^{\circ}\text{C to } 175^{\circ}\text{C}, R_{GS} = 1\text{M}\Omega$	40	V
V <sub>GSM</sub>	Transient	±20	V
I <sub>D25</sub>	T <sub>C</sub> = 25°C	300	A
I <sub>L(RMS)</sub>	External Lead Current Limit	120	Α
I <sub>DM</sub>	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	900	Α
I <sub>A</sub>	T <sub>c</sub> = 25°C	100	A
E <sub>as</sub>	$T_{c} = 25^{\circ}C$	600	mJ
$P_{D}$	T <sub>C</sub> = 25°C	480	W
T		-55 +175	°C
T <sub>JM</sub>		175	°C
T <sub>stg</sub>		-55 +175	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering	g 300	°C
T <sub>SOLD</sub>	1.6 mm (0.062in.) from Case for 10s	260	°C
F <sub>c</sub>	Mounting Force (TO-263)	1065 / 2.214.6	N/lb
Md	Mounting Torque (TO-220)	1.13 / 10	Nm/lb.in
Weight	TO-263	2.5	g
	TO-220	3.0	g

TO-220	(IXTP	")
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G = Gate	D	=	Drain
S = Source	Tab	=	Drain

#### **Features**

- International Standard Packages
- Avalanche Rated
- Low Package Inductance
- Fast Intrinsic Rectifier 175°C Operating Temperature
- High Current Handling Capability
- ROHS Compliant
- High Performance Trench Technology for extremely low  $R_{\scriptscriptstyle DS(on)}$

<b>Symbol Test Conditions</b> $(T_J = 25^{\circ}C \text{ Unless Otherwise Specified})$			acteristi   Typ.	c Values Max.	
BV <sub>DSS</sub>	$V_{GS} = 0V, I_{D} = 250\mu A$	40			١
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.0		4.0	١

#### $V_{GS} = \pm 20V, V_{DS} = 0V$ ±200 nΑ l<sub>gss</sub> $V_{DS} = V_{DSS}, V_{GS} = 0V$ 5 μΑ DSS T<sub>J</sub> = 150°C 150 μΑ $V_{GS} = 10V$ , $I_{D} = 150A$ , Notes 1 & 2 $R_{_{D\underline{S(on)}}}$ $2.5~\text{m}\Omega$

### **Advantages**

- High Power Density
- Easy to Mount
- Space Savings

### **Applications**

- Automotive Engine Control
- Synchronous Buck Converter (for Notebook SystemPower & General Purpose Point & Load)
- DC/DC Converters
- High Current Switching Applications
- Power Train Management
- Distributed Power Architecture



		Char Min.	racteristic Values   Typ.   Max.		
(1) - 20		пеза отпетиве оресписа)	141111.	Typ.	Wax.
$\mathbf{g}_{fs}$		$V_{DS} = 10V, I_{D} = 60A, Note 1$	55	94	S
C <sub>iss</sub>	)			10.7	nF
C <sub>oss</sub>	}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		1630	pF
$\mathbf{C}_{rss}$	J			263	pF
t <sub>d(on)</sub>	٦	Deciative Contabine Times		22	ns
t,	(	Resistive Switching Times		17	ns
$\mathbf{t}_{d(off)}$	1	$V_{GS} = 10V, V_{DS} = 20V, I_{D} = 100A$		32	ns
t,	)	$R_{_{G}} = 2\Omega$ (External)		13	ns
$\mathbf{Q}_{g(on)}$	)			145	nC
$\mathbf{Q}_{gs}$	}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{DSS}$		44	nC
$\mathbf{Q}_{gd}$	J			36	nC
R <sub>thJC</sub>					0.31 °C/W
R <sub>thCS</sub>		TO-220		0.50	°C/W

#### Source-Drain Diode

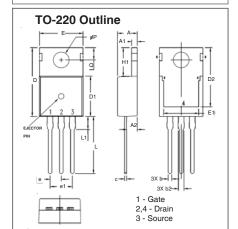
SymbolTest ConditionsChara $(T_J = 25^{\circ}C \text{ Unless Otherwise Specified})$ Min.			cteristic Typ.	Values Max.	·
Is	$V_{GS} = 0V$			300	Α
I <sub>SM</sub>	Repetitive, Pulse Width Limited by $T_{_{JM}}$			1000	Α
V <sub>SD</sub>	$I_F = 100A$ , $V_{GS} = 0V$ , Note 1			1.1	V
t <sub>rr</sub>	1 1504 // 0//		53		ns
I <sub>RM</sub>	$I_{F} = 150A, V_{GS} = 0V,$ $-di/dt = 100A/\mu s, V_{B} = 20V$		1.8		Α
Q <sub>RM</sub>	$-\alpha I/\alpha t = 100A/\mu s$ , $v_R = 20V$		47.7		nC

Notes: 1. Pulse test,  $t \le 300 \mu s$ ; duty cycle,  $d \le 2\%$ .

2. On through-hole packages,  $R_{\mathrm{DS(on)}}$  Kelvin test contact location must be 5mm or less from the package body.

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SYM	INCHES		MILLIMETER		
SIM	MIN	MAX	MIN	MAX	
Α	.170	.185	4.30	4.70	
A1	.000	.008	0.00	0.20	
A2	.091	.098	2.30	2.50	
Ь	.028	.035	0.70	0.90	
b2	.046	.060	1.18	1.52	
С	.018	.024	0.45	0.60	
C2	.049	.060	1.25	1.52	
D	.340	.370	8.63	9.40	
D1	.300	.327	7.62	8.30	
E	.380	.410	9.65	10.41	
E1	.270	.330	6.86	8.38	
е	.100	BSC	2.54	BSC	
Н	.580	.620	14.73	15.75	
L	.075	.105	1.91	2.67	
L1	.039	.060	1.00	1.52	
L2	_	.070	_	1.77	
L3	.010	.010 BSC		BSC	



SYM INCHES		MILLIMETERS		
MIN	MAX	MIN	MAX	
.169	.185	4.30	4.70	
.047	.055	1.20	1.40	
.079	.106	2.00	2.70	
.024	.039	0.60	1.00	
.045	.057	1.15	1.45	
.014	.026	0.35	0.65	
.587	.626	14.90	15.90	
.335	.370	8.50	9.40	
.500	.531	12.70	13.50	
.382	.406	9.70	10.30	
.283	.323	7.20	8.20	
.100 BSC		2.54	BSC	
.200	BSC	5.08 BSC		
.244	.268	6.20	6.80	
.492	.547	12.50	13.90	
.110	.154	2.80	3.90	
.134	.150	3.40	3.80	
.106	.126	2.70	3.20	
	MIN .169 .047 .079 .024 .045 .014 .587 .335 .500 .382 .283 .100 .200 .244 .492 .110	MIN MAX .169 .185 .047 .055 .079 .106 .024 .039 .045 .057 .014 .026 .587 .626 .335 .370 .500 .531 .382 .406 .283 .323 .100 BSC .200 BSC .244 .268 .492 .547 .110 .154 .134 .150	MIN         MAX         MIN           .169         .185         4.30           .047         .055         1.20           .079         .106         2.00           .024         .039         0.60           .045         .057         1.15           .014         .026         0.35           .587         .626         14.90           .335         .370         8.50           .500         .531         12.70           .382         .406         9.70           .283         .323         7.20           .100 BSC         2.54           .200 BSC         5.08           .244         .268         6.20           .492         .547         12.50           .110         .154         2.80           .134         .150         3.40	

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.



Fig. 1. Output Characteristics @ T<sub>J</sub> = 25°C

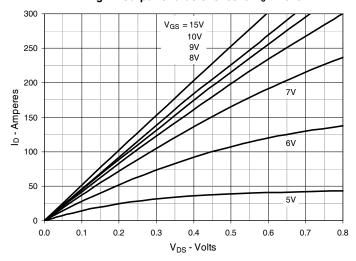


Fig. 2. Extended Output Characteristics @ T<sub>J</sub> = 25°C

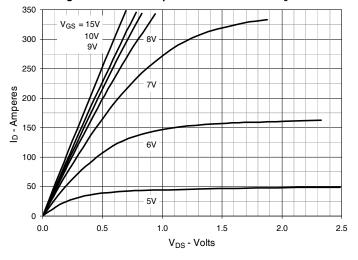


Fig. 3. Output Characteristics @  $T_J = 150^{\circ}C$ 

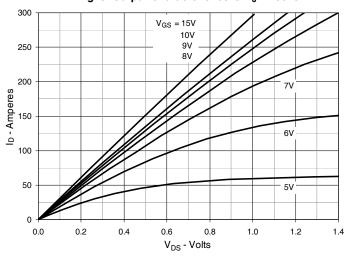


Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D$  = 150A Value vs. Junction Temperature

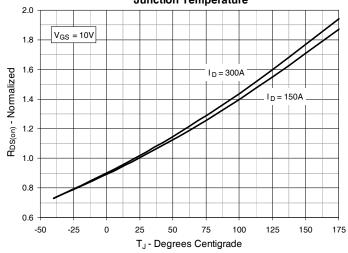


Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D$  = 150A Value vs.

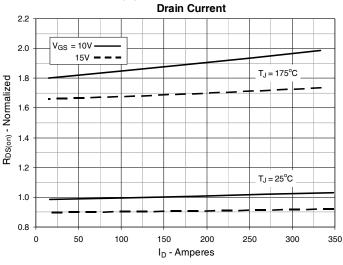
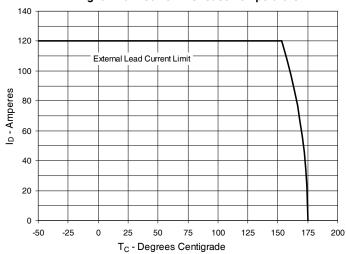
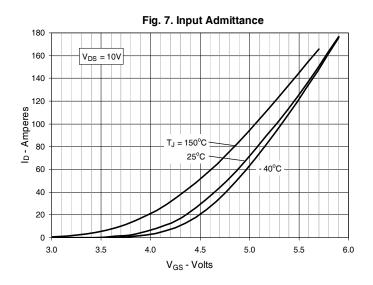
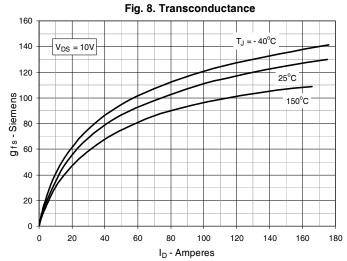


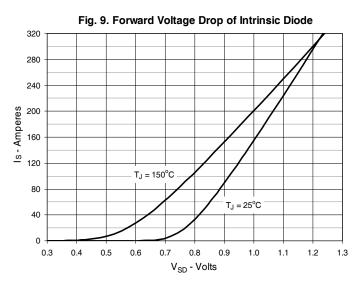
Fig. 6. Drain Current vs. Case Temperature

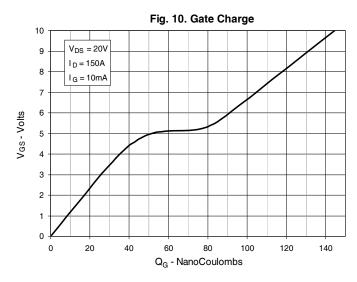


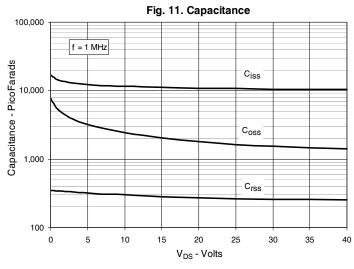


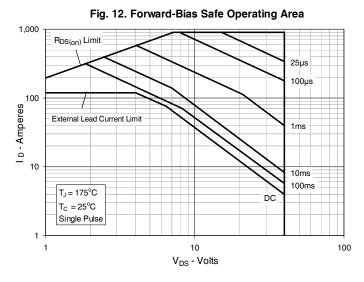












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T<sub>J</sub> - Degrees Centigrade

Fig. 14. Resistive Turn-on Rise Time vs. Drain Current  $R_G = 2\Omega$ ,  $V_{GS} = 10V$  $V_{DS} = 20V$  $T_J = 125^{\circ}C$ tr-Nanoseconds  $T_J = 25^{\circ}C$  $I_D$  - Amperes

Fig. 15. Resistive Turn-on Switching Times vs. Gate Resistance  $T_J = 125^{\circ}C$ ,  $V_{GS} = 10V$  $V_{DS} = 20V$ ر <sub>d(on)</sub> - Nanoseconds 55 ي tr-Nanoseconds R<sub>G</sub> - Ohms

